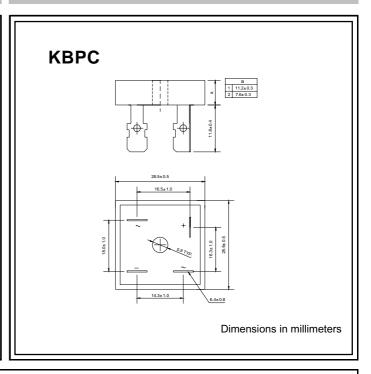
# SILICON BRIDGE RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V CURRENT: 10.0 A

## **FEATURES**

- ♦ Surge overload rating to 150 Amperes peak
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ♦ Mounting: thru hole for # 6 screw mounting



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

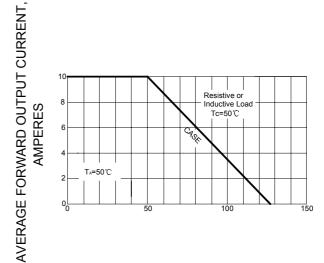
		KBPC 10005	KBPC 1001	KBPC 1002	KBPC 1004	KBPC 1006	KBPC 1008	KBPC 1010	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forw ard  Output current @T <sub>A</sub> =50℃	I <sub>F(AV)</sub>				10.0				А
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I <sub>FSM</sub>	150.0							А
Maximum instantaneous forw ard voltage  @ 5.0 A	V <sub>F</sub>	1.1					V		
Maximum reverse current $@T_A = 25 ^{\circ}C$ at rated DC blocking voltage $@T_A = 100 ^{\circ}C$	I <sub>R</sub>	10.0 1.0							μA mA
Operating junction temperature range	$T_J$	- 55 + 125							${\mathbb C}$
Storage temperature range	T <sub>STG</sub>	- 55 + 150							$^{\circ}$

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### FIG.1 - PEAK FORWARD SURGE CURRENT

NUMBER OF CYCLES AT 60Hz

# FIG.2 - FORWARD DERATING CURVE



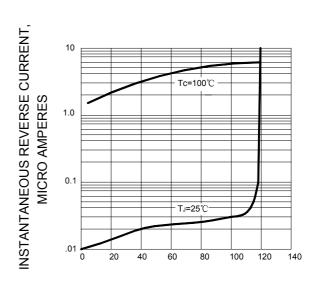
AMBIENT TEMPERATURE, °C

#### FIG.3 - TYPICAL FORWARD CHARACTERISTIC

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INSTANTANEOUS FORWARD VOLTAGE, VOLTS

#### FIG.4 - TYPICAL REVERSE CHARACTERISTIC



PERCENT OF RATED PEAK REVERSE VOLTAGE

INSTANTANEOUS FORWARD CURRENT,

**AMPERES**